Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
0.300 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.130 inches	
Joint Electronic De	evice Engineering Council/jedec/case Outline Designation:
Do-7	
Mounting Method:	
Terminal	
Features Provided:	:
Hermetically sealed	case
Semiconductor Ma	terial:
Silicon	
Voltage Rating In \	/olts Per Characteristic:
11.7 regulator volta	age
Current Rating Per	Characteristic:
45.00 milliamperes	source cutoff current horsepower metric
Power Rating Per (Characteristic:
500.0 milliwatts sma	all-signal input power, common-collector preset
Maximum Operatin	ng Tempurature Per Measurement Point:
175.0 degrees celsi	us ambient air
Precious Material	And Location:
Leads gold	
Precious Material:	
Gold	
Test Data Docume	nt:
81349-mil-s-19500 s	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes co	mmercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and p	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	Quantity:
2 uninsulated wire le	ead
Specification Data:	
81349-mil-s-19500/ ²	157 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
A110a0	